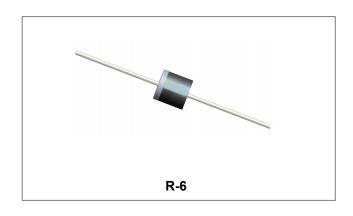






ST1050AX SCHOTTKY BARRIER RECTIFIER



Features

- 150°C T_J operation
- Center tap configuration
- Ultralow forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- · High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{R} \end{array}$	-	50	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @T _C = 75°C, rectangular wave form	10	Α
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse, T _C = 25°C	150	Α

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 5A, Pulse, T _J = 25 °C @ 10A, Pulse, T _J = 25 °C	0.43 0.49	- 0.55	V
	V _{F2}	@ 5A, Pulse, T _J = 125 °C @ 10A, Pulse, T _J = 125 °C	0.30 0.39	- 0.49	V
Reverse Current*	I _{R1}	@V _R = rated V _R , T _J = 25 °C	0.02	1.5	mA
	I _{R2}	@V _R = rated V _R , T _J = 125 °C	9	85	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	500	-	pF

 $^{^*}$ Pulse width < 300 μ s, duty cycle < 2%

- China Germany Korea Singapore United States •
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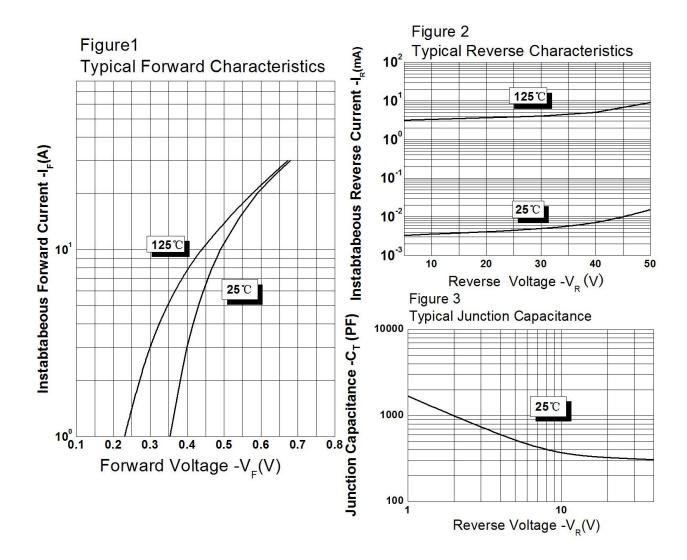




Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Ambient	$R_{ heta JA}$	DC operation	45	°C/W
Approximate Weight	wt	-	0.08	g
Case Style	R-6			

Ratings and Characteristics Curves



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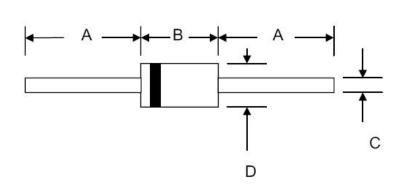
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Mechanical Dimensions R-6



CVMPOL	Millimeters		Inches		
SYMBOL	Min.	Max.	Min.	Max.	
А	25.4	-	1.000	-	
В	8.60	9.10	0.340	0.360	
С	1.2	1.3	0.048	0.052	
D	8.60	9.10	0.340	0.360	

Ordering Information

Device	Package	Shipping
ST1050AX	R-6(Pb-Free)	500pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram

Where XXXXX is YYWWL

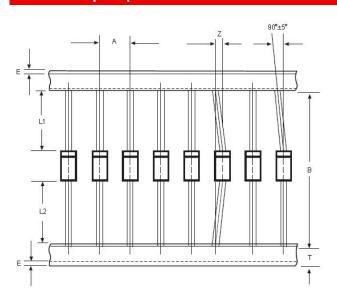
S = Device Type
T = Ultralow VF
10 = Forward Current (10A)
50 = Reverse Voltage (50V)
AX = Package type

SSG = SSG
YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Carrier Tape Specification R-6



SYMBOL	Millimeters		
STINIBUL	Min.	Max.	
А	9.50	10.50	
В	50.9	53.9	
Z	-	1.20	
Т	5.60	6.40	
E	-	0.80	
IL1-L2I	-	1.0	

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